



DMG1013UWQ

P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- **PPAP Capable (Note 4)**

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020 •
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)



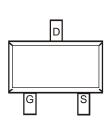


Top View



Equivalent Circuit

Drain



Top View

Ordering Information (Note 5)

| Part Number | Case | Packaging |
|---------------|--------|---------------------|
| DMG1013UWQ-7 | SOT323 | 3000 / Tape & Reel |
| DMG1013UWQ-13 | SOT323 | 10000 / Tape & Reel |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

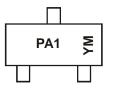
Notes:

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



PA1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: D = 2016)M = Month (ex: 9 = September)

Date Code Key

| Year | 2008 | | 2015 | 2016 | 2017 | 2018 | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 |
|-------|------|-----|-------|------|------|---|------|------|------|------|------|------|
| Code | V | | С | D | E | F | G | Н | | J | К | L |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| month | Vull | 100 | intai | 1.0 | | • | | | | | | |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Chara | Symbol | Value | Unit | | |
|-----------------------------------|------------------|--|------|----------------|---|
| Drain-Source Voltage | V _{DSS} | -20 | V | | |
| Gate-Source Voltage | V _{GSS} | ±6 | V | | |
| Continuous Drain Current (Note 6) | Steady State | T _A = +25°C T _A = +85°C | ID | -0.82 -0.54 | A |
| Pulsed Drain Current (Note 7) | I _{DM} | -3 | A | | |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 6) | PD | 0.31 | W |
| Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6) | R _{0JA} | 398 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

 Device mounted on FR-4 PCB, with minimum recommended pad layout.
Repetitive rating, pulse width limited by junction temperature. Notes:

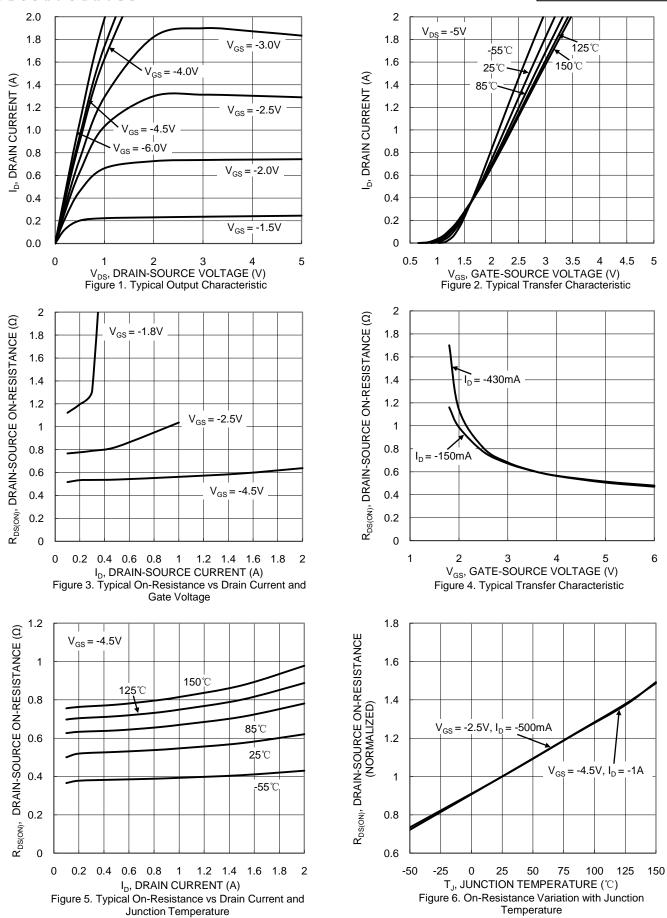
Flectrical Characteristics (@T_A = +25°C. unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|---------------------|------|-------|-------------|------|---|
| OFF CHARACTERISTICS (Note 8) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | - | - | V | $V_{GS} = 0V, I_D = -250\mu A$ |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | - | - | -100 | nA | $V_{DS} = -20V, V_{GS} = 0V$ |
| Gate-Source Leakage | IGSS | - | - | ±2.0 | μA | $V_{GS} = \pm 4.5 V, V_{DS} = 0 V$ |
| ON CHARACTERISTICS (Note 8) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.5 | - | -1.0 | V | $V_{DS} = V_{GS}$, $I_D = -250 \mu A$ |
| | | - | 0.5 | 0.75 | | $V_{GS} = -4.5V, I_D = -430mA$ |
| Static Drain-Source On-Resistance | R _{DS(ON)} | | 0.7 | 1.05 1.5 | Ω | $V_{GS} = -2.5V, I_D = -300mA$ |
| | | | 1.0 | | | $V_{GS} = -1.8V, I_D = -150mA$ |
| Forward Transfer Admittance | Y _{fs} | - | 0.9 | - | S | $V_{DS} = -10V, I_D = -250mA$ |
| Diode Forward Voltage | V _{SD} | | -0.8 | -1.2 | V | $V_{GS} = 0V, I_{S} = -150mA$ |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | |
| Input Capacitance | Ciss | - | 59.76 | - | pF | |
| Output Capacitance | Coss | - | 12.07 | - | pF | ─V _{DS} = -16V, V _{GS} = 0V, ─f = 1.0MHz |
| Reverse Transfer Capacitance | C _{rss} | - | 6.36 | - | pF | 1 = 1.0001 IZ |
| Total Gate Charge | Qg | - | 622.4 | - | рС | |
| Gate-Source Charge | Q _{gs} | - | 100.3 | - | рС | $V_{GS} = -4.5V, V_{DS} = -10V,$ |
| Gate-Drain Charge | Q _{gd} | - | 132.2 | - | рС | – I _D = -250mA |
| Turn-On Delay Time | t _{D(ON)} | - | 5.1 | - | ns | |
| Turn-On Rise Time | t _R | - | 8.1 | - | ns | $V_{DD} = -10V, V_{GS} = -4.5V,$ |
| Turn-Off Delay Time | t _{D(OFF)} | - | 28.4 | - | ns | $R_{L} = 47\Omega, R_{G} = 10\Omega,$ $D_{D} = -200 \text{mA}$ |
| Turn-Off Fall Time | t _F | - | 20.7 | - | ns | D = -200 mA |

8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to production testing. Notes:



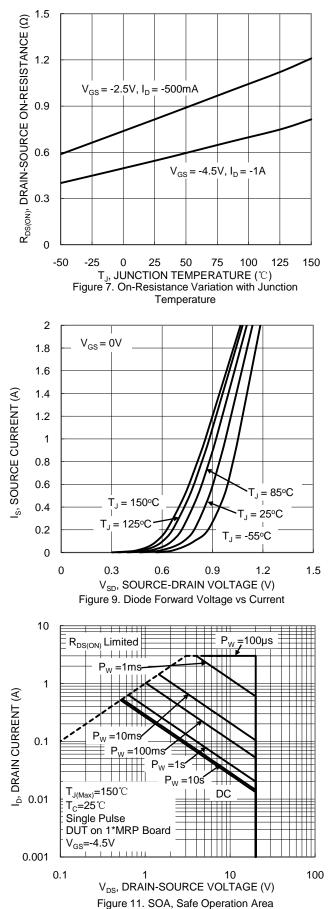
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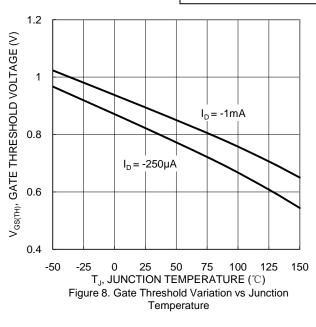


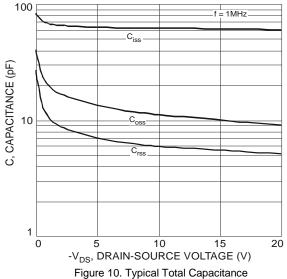
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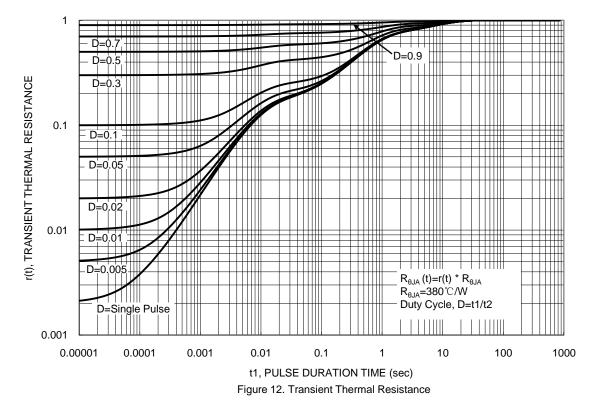
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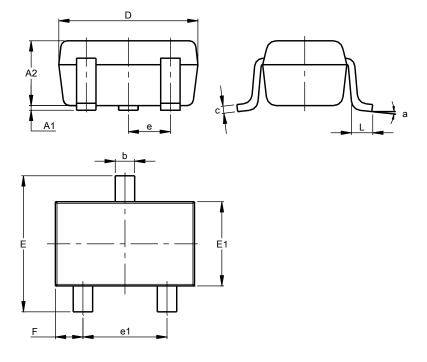




Package Outline Dimensions

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.

SOT323

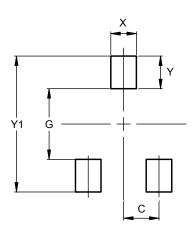


| | SOT323 | | | | | | |
|-----|-----------|-------|-------|--|--|--|--|
| Dim | Min | Max | Тур | | | | |
| A1 | 0.00 | 0.10 | 0.05 | | | | |
| A2 | 0.90 | 1.00 | 0.95 | | | | |
| b | 0.25 | 0.40 | 0.30 | | | | |
| С | 0.10 | 0.18 | 0.11 | | | | |
| D | 1.80 | 2.20 | 2.15 | | | | |
| E | 2.00 | 2.20 | 2.10 | | | | |
| E1 | 1.15 | 1.35 | 1.30 | | | | |
| е | 0.650 BSC | | | | | | |
| e1 | 1.20 | 1.40 | 1.30 | | | | |
| F | 0.375 | 0.475 | 0.425 | | | | |
| L | 0.25 | 0.40 | 0.30 | | | | |
| а | | 8° | | | | | |
| All | Dimen | sions | in mm | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.

SOT323



| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.650 |
| G | 1.300 |
| Х | 0.470 |
| Y | 0.600 |
| Y1 | 2.500 |



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